DIOTEC ELECTRONICS CORP.

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35 AMP SILICON BRIDGE RECTIFIERS

FEATURES

- PRV Ratings from 50 to 1000 Volts
- Surge overload rating to 400 Amps peak
- High efficiency
- Heat sink integrally mounted in the molded bridge encapsulation

UL RECOGNIZED - FILE #E141956

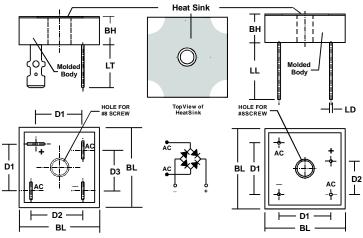
MECHANICAL DATA

- Case: Molded plastic, U/L Flammability Rating 94V-0
- Terminals: Round silver plated copper pins or fast-on terminals
- Soldering: Per MIL-STD 202 Method 208 guaranteed (Note 1)
- Polarity: Marked on side of case
- Mounting Position: Any. Through hole for #8 screw. Max. mounting torque = 20 in-lb.
- Weight: Fast-on Terminals 0.7 Ounces (20.0 Grams) Wire Leads - 0.55 Ounces (16.0 Grams)

MECHANICAL SPECIFICATION

SERIES: DB3500P - DB3510P and ADB3504P - ADB3508P

Suffix "P" indicates molded PLASTIC with intergrally mounted Heat Sink



SYM	MILLIMETERS		INCHES					
	MIN	MAX	MIN	MAX				
BL	28.4	28.7	1.12	1.13				
BH	9.6	9.8	0.38	0.39				
D1	15.7	16.7	0.62	0.66				
D2	17.5	18.5	0.69	0.73				
D3	13.5	14.5	0.53	0.57				
LT	n/a	15.2	n/a	0.6				

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	MIN	MAX	MIN	MAX				
BL	28.4	28.7	1.12	1.13				
BH	9.6	9.8	0.38	0.39				
D1	17.5	18.5	0.69	0.73				
D2	10.9	11.9	0.43	0.47				
LL	20.6	n/a	0.81	n/a				
LD	1.0	1.1	0.039	0.042				

Suffix "T" indicates FAST-ON TERMINALS

Suffix "W" indicates WIRE LEADS

MAXIMUM RATINGS & ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive loads, derate current by 20%

PARAMETER (TEST CONDITIONS)		RATINGS										
		CONTROLLED NON-CONTROLLED AVALANCHE AVALANCHE								UNITS		
Series Number				ADB 3508P		DB 3501P	DB 3502P	DB 3504P	DB 3506P	DB 3508P	DB 3510P	
Maximum DC Blocking Voltage	Vrm	400 600 800						400	600	800	1000	VOLTS
Working Peak Reverse Voltage	Vrwm			800	50	100	200					
Maximum Peak Recurrent Reverse Voltage	Vrrm											
RMS Reverse Voltage	VR (RMS)	280	420	560	35	70	140	280	420	560	700	
Thermal Energy (Rating for Fusing)	l²t	664								AMPS ² SEC		
Peak Forward Surge Current (8.3 mSec single half sine wave superimposed on rated load) IFSM 400							AMPS					
Average Forward Rectified Current @ Tc = 55 °C (Note 2)	lo	35								/		
Junction Operating and Storage Temperature Range	TJ, TSTG	-55 to +150							°C			
Mimimum Avalanche Voltage	V(BR) Min	450 650 850 n/a										
Maximum Avalanche Voltage	V(BR) Max	900	1100	1300		n/a					VOLTS	
Maximum Forward Voltage (Per Diode) at 17.5 Amps DC	VFM	1.1										
Maximum Reverse Current at Rated VRM @ TA = 25°C @ TA = 100°C	IRM	1 5								μ Α		
Minimum Insulation Breakdown Voltage (Circuit to Case)	Viso	2500								VOLTS		
Typical Thermal Resistance (on Heat Sink); Junction to Ambient (Note 3)	R⊕JC R⊕JL	1.2 0.8							°C/W			

NOTES: (1) Maximum soldering time and temperature = 10 Sec @ 265°C

(2) Unit Mounted on Metal Chassis.
(3) Mounted on an 11.8 in. 2 x 0.06 in. thick (300mm² x 1.5mm thick) copper plate.